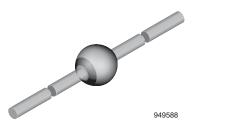
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1N5624, 1N5625, 1N5626, 1N5627

Vishay Semiconductors

Standard Avalanche Sinterglass Diode



DESIGN SUPPORT TOOLS



S click logo to get started

MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

Mounting position: any

Weight: approx. 858 mg

FEATURES

- Glass passivated junction
- · Hermetically sealed package
- · Controlled avalanche characteristics
- Low reverse current
- High surge current loading
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Rectification diode, general purpose

ORDERING INFORMATION (Example)					
DEVICE NAME ORDERING CODE TAPED UNITS MINIMUM ORDER O			MINIMUM ORDER QUANTITY		
1N5627	1N5627-TR	2500 per 10" tape and reel	12 500		
1N5627	1N5627-TAP	2500 per ammopack	12 500		

PARTS TABLE		
PART	TYPE DIFFERENTIATION	PACKAGE
1N5624	V _R = 200 V; I _{F(AV)} = 3 A	SOD-64
1N5625	$V_{R} = 400 \text{ V}; \text{ I}_{F(AV)} = 3 \text{ A}$	SOD-64
1N5626	$V_{R} = 600 \text{ V}; I_{F(AV)} = 3 \text{ A}$	SOD-64
1N5627	V _R = 800 V; I _{F(AV)} = 3 A	SOD-64

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
	See electrical characteristics	1N5624	$V_R = V_{RRM}$	200	V
Reverse voltage = repetitive peak reverse		1N5625	$V_R = V_{RRM}$	400	V
voltage		1N5626	$V_R = V_{RRM}$	600	V
		1N5627	$V_{R} = V_{RRM}$	800	V
Peak forward surge current	t _p = 10 ms, half sine wave		I _{FSM}	100	А
Repetitive peak forward current			I _{FRM}	18	А
Average forward current			I _{F(AV)}	3	А
Pulse avalanche peak power	t _p = 20 µs, half sine wave, T _j = 175 °C		P _R	1000	W
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	I _{(BR)R} = 1 A, T _j = 175 °C		E _R	20	mJ
i ² *t-rating			i ² *t	40	A²*s
Junction and storage temperature range			$T_j = T_{stg}$	-55 to +175	°C

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MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION SYMBOL VALUE		UNIT		
Junction ambient	I = 10 mm, T _L = constant	R _{thJA}	25	K/W	
	On PC board with spacing 25 mm	R _{thJA}	70	K/W	

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 3 A		V _F	-	-	1	V
Reverse current	$V_{R} = V_{RRM}$		I _R	-	0.1	1	μA
neverse current	$V_{R} = V_{RRM}, T_{j} = 100 \ ^{\circ}C$		I _R	-	5	10	μA
Breakdown voltage	$ I_{\rm R} = 100 \; \mu {\rm A}, t_p / T = 0.01, \\ t_p = 0.3 \; ms $		V _(BR)	-	-	1600	V
Diode capacitance	$V_R = 4 V, f = 1 MHz$		CD	-	40	60	pF
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, i_R = 0.25 \text{ A}$		t _{rr}	-	3.5	5	μs
Reverse recovery time	$I_F = 1 \text{ A}, d_l/d_t = 5 \text{ A}/\mu \text{s}, V_R = 50 \text{ V}$		t _{rr}	-	4.5	7.5	μs
Reverse recovery charge	$I_F = 1 \text{ A}, d_I/d_t = 5 \text{ A}/\mu \text{s}$		Q _{rr}	-	8	12	μC

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

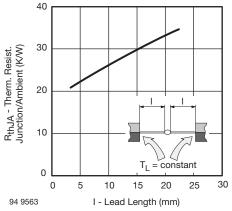
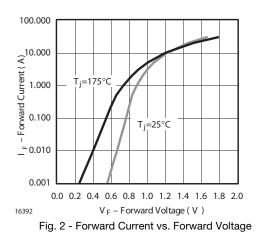


Fig. 1 - Max. Thermal Resistance vs. Lead Length



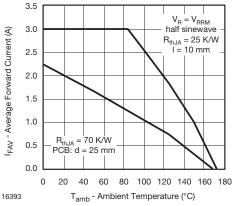


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

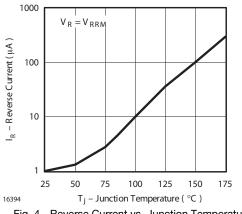


Fig. 4 - Reverse Current vs. Junction Temperature

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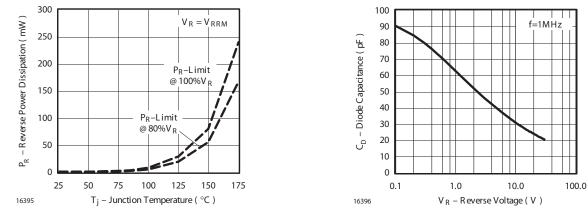
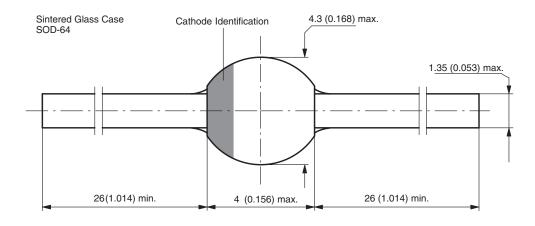


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

Fig. 6 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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